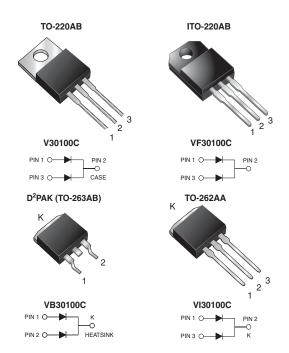


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# Dual High Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.455 \text{ V}$  at  $I_F = 5 \text{ A}$ 



### **ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 15 A					
V <sub>RRM</sub>	100 V					
I <sub>FSM</sub>	160 A					
V <sub>F</sub> at I <sub>F</sub> = 15 A	0.63 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

#### **FEATURES**

Trench MOS Schottky technology



• Low forward voltage drop, low power losses



High efficiency operation
Mosts
MSI
lovel

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)

· Low thermal resistance

- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB,  $D^2PAK$  (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	V30100C	VF30100C	VB30100C	VI30100C	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	100				V		
Maximum average forward rectified current (fig. 1)	per device		30				^	
	per diode	I <sub>F(AV)</sub>		15			A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	160			Α		
Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, L = 60 mH per diode		E <sub>AS</sub>	210				mJ	
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, $T_J$ = 38 °C $\pm$ 2 °C per diode		I <sub>RRM</sub>	1.0		Α			
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500			V		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150				°C	

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PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP.	TYP. MAX.	
Breakdown voltage	I <sub>R</sub> = 10 mA	T <sub>A</sub> = 25 °C	$V_{BR}$	100 (minimum)	-	V
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A		V <sub>F</sub> <sup>(1)</sup>	0.516	=	V
	I <sub>F</sub> = 7.5 A	T <sub>A</sub> = 25 °C		0.576	=	
	I <sub>F</sub> = 15 A			0.734	0.80	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.455	=	
	I <sub>F</sub> = 7.5 A			0.522	=	
	I <sub>F</sub> = 15 A			0.627	0.68	
Reverse current per diode	V <sub>R</sub> = 70 V	T <sub>A</sub> = 25 °C		7.2	-	μΑ
		T <sub>A</sub> = 125 °C	1 (2)	8.0	=	mA
	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	65	500	μΑ
		T <sub>A</sub> = 125 °C		20	35	mA

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER SYMBOL V30100C VF30100C VB30100C VI30100C U					UNIT		
Typical thermal resistance per diode	$R_{ heta JC}$	2.5	5.5	2.5	2.5	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30100C-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF30100C-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB30100C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB30100C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI30100C-E3/4W	1.46	4W	50/tube	Tube			

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

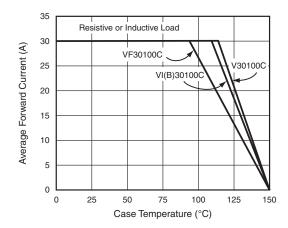


Fig. 1 - Forward Current Derating Curve

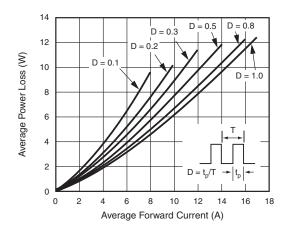


Fig. 2 - Forward Power Loss Characteristics Per Diode

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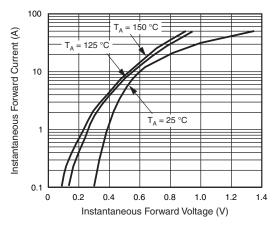


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

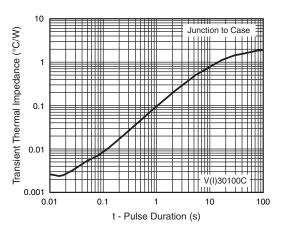


Fig. 6 - Typical Transient Thermal Impedance Per Diode

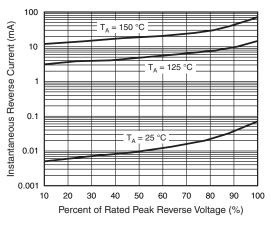


Fig. 4 - Typical Reverse Characteristics Per Diode

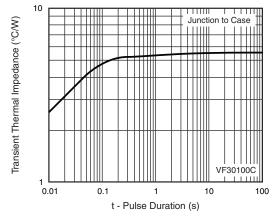


Fig. 7 - Typical Transient Thermal Impedance Per Diode

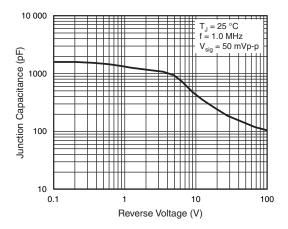


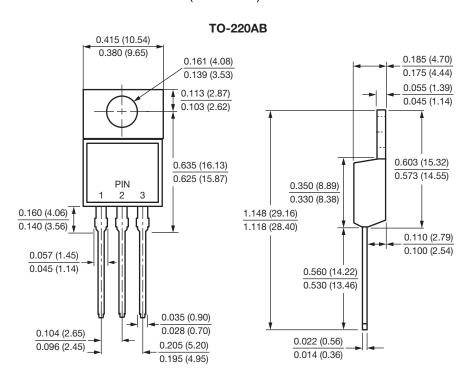
Fig. 5 - Typical Junction Capacitance

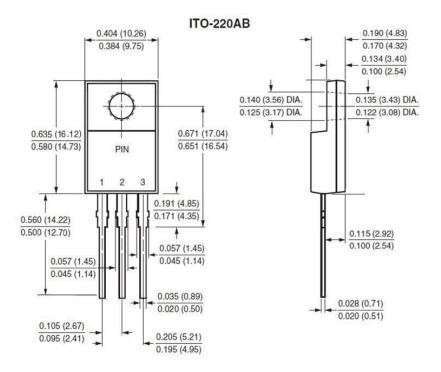


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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





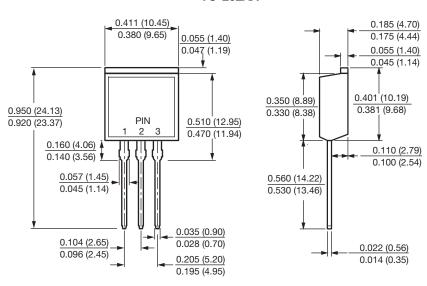
Revision: 15-Oct-2019 **4** Document Number: 89010 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>



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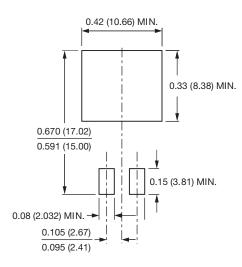
#### **TO-262AA**



### D<sup>2</sup>PAK (TO-263AB)

#### 0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.055 (1.40) 0.160 (4.06) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 12 Κ 0.591 (15.00) -0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

### **Mounting Pad Layout**



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